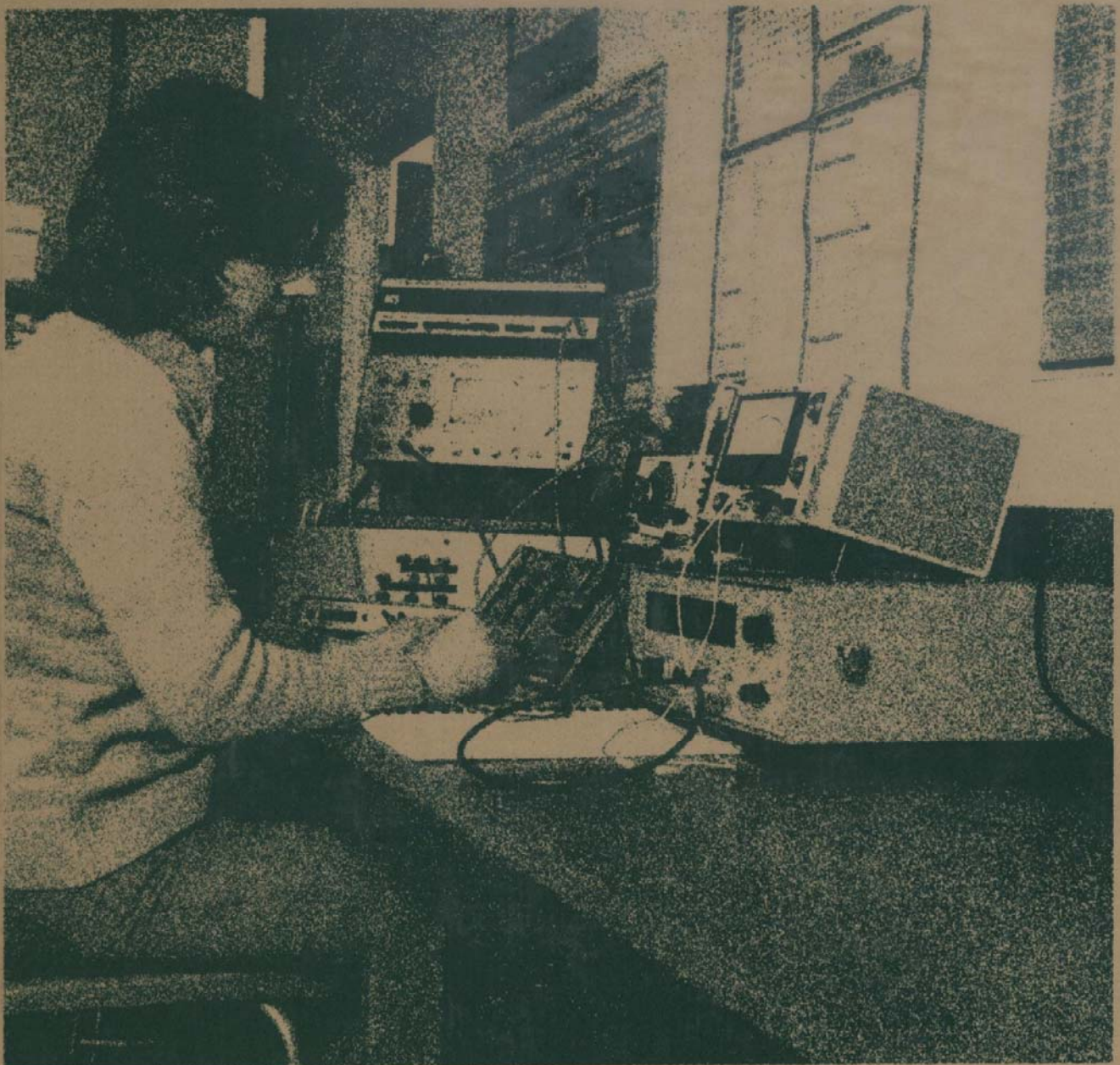


EXPERIMENTAL ELECTRONICS FOR STUDENTS

K.J. Close J. Yarwood



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